



FUKUCOM COMPANY LTD.

福 靈 有 限 公 司

FLAT P, 3/F., EVEREST INDUSTRIAL CENTRE, 396 KWUN TONG ROAD,
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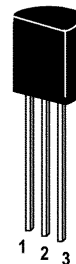
ST 2SB772S

PNP Silicon Epitaxial Transistor

Medium Power Low Voltage Transistor

The transistor is subdivided into three groups Q, P and E, according to its DC current gain.

On special request, these transistors can be manufactured in different pin configurations.



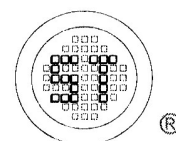
1. Emitter 2. Collector 3. Base
TO-92 Plastic Package
Weight approx. 0.19g

Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	-V _{CB0}	40	V
Collector-Emitter Voltage	-V _{CE0}	30	V
Emitter-Base Voltage	-V _{EB0}	5	V
Collector Current	-I _C	3	A
Peak Collector Current	-I _{CM}	7	A
Base Current	-I _B	600	mA
Collector Dissipation	P _{tot}	500	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _s	- 55 to + 150	°C

Characteristics (T_a = 25 °C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	
DC Current Gain at -V _{CE} = 2 V, -I _C = 1 A at -V _{CE} = 2 V, -I _C = 20 mA	Current Gain Group Q	h _{FE}	100	-	200	-
	P	h _{FE}	160	-	320	-
	E	h _{FE}	200	-	400	-
		h _{FE}	30	-	-	-
Collector Cutoff Current at -V _{CB} = 30 V	-I _{CB0}	-	-	1	μA	
Emitter Cutoff Current at -V _{EB} = 3 V	-I _{EB0}	-	-	1	μA	
Collector-Emitter Saturation Voltage at -I _C = 2 A, -I _B = 200 mA	-V _{CE(sat)}	-	-	0.5	V	
Base-Emitter Saturation Voltage at -I _C = 2 A, -I _B = 200 mA	-V _{BE(sat)}	-	-	2	V	
Current Gain Bandwidth Product at -V _{CE} = 5 V, -I _C = 0.1 A	f _T	-	80	-	MHz	
Output Capacitance at -V _{CB} = 10 V, f = 1 MHz	C _{ob}	-	45	-	pF	



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Dated : 04/10/2006



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Fig.1 Static characteristics

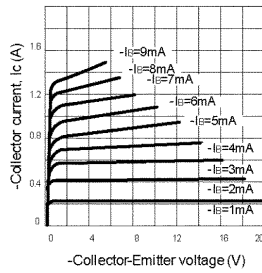


Fig.2 Derating curve of safe operating areas

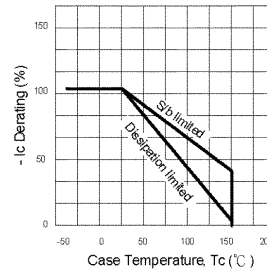


Fig.3 Power Derating

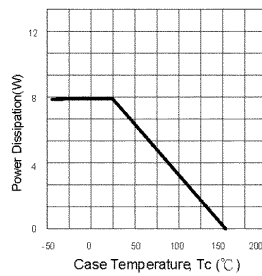


Fig.4 Collector Output capacitance

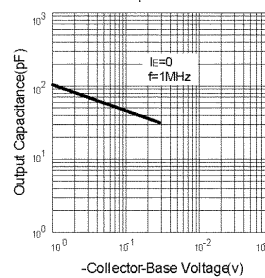


Fig.5 Current gain-bandwidth product

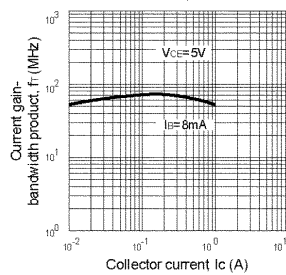


Fig.6 Safe Operating Area

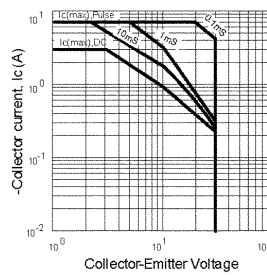


Fig.7 DC current gain

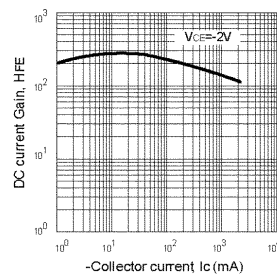
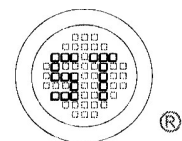
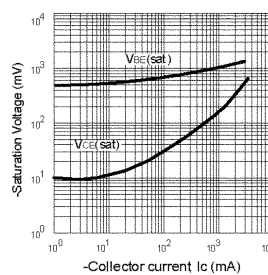


Fig.8 Saturation Voltage



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